BU4523DW

GENERAL DESCRIPTION

Enhanced performance, new generation, high-voltage, high-speed switching npn transistor in a plastic envelope with an integrated damper diode intended for use in horizontal deflection circuits of colour television receivers and p.c monitors. Features exceptional tolerance to base drive and collector current load variations resulting in a very low worst case dissipation.

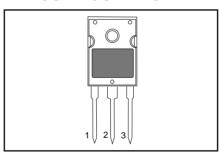
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V_{CESM}	Collector-emitter voltage peak value	$V_{BF} = 0 \text{ V}$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)		-	800	V
I _C	Collector current (DC)		-	11	Α
1 1	Collector current peak value		-	29	Α
P _{tot}	Total power dissipation	$T_{hs} \le 25 ^{\circ}C$ $I_{C} = 8 A; I_{B} = 2 A$	-	125	W
V _{CEsat}	Collector-emitter saturation voltage	$I_{\rm C} = 8 \text{A}; I_{\rm B} = 2 \text{A}$	-	3.0	V
Csat	Collector saturation current.	f = 16 kHz	8	-	Α
Cour		f = 70 kHz	6.5	-	Α
V_{F}	Diode forward voltage	$I_{\rm F} = 8.0 {\rm A}$	-	2.2	V
t,	Fall time	I _{Csat} = 8 A; f = 16 kHz f = 70 kHz	0.3	0.4	μs
		f = 70 kHz	t.b.f	t.b.f	μs

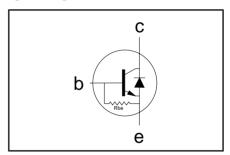
PINNING - SOT429

PIN	DESCRIPTION	
1	base	
2	collector	
3	emitter	
tab	collector	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 \text{ V}$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)		-	800	V
I _C	Collector current (DC)		-	11	Α
I _{CM}	Collector current peak value		-	29	Α
I _B	Base current (DC)		-	7	Α
I I _{BM}	Base current peak value		-	10	Α
- I _{BM}	Reverse base current peak value 1		-	7	Α
P _{tot}	Total power dissipation	$T_{hs} \leq 25 ^{\circ}C$	-	125	W
T _{stq}	Storage temperature	113	-55	150	°C
Tj	Junction temperature		-	150	°C

¹ Turn-off current.

BU4523DW

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-mb}	Junction to mounting base	with heatsink compound	ı	1	K/W
R _{th j-a}	Junction to ambient	in free air	45	-	K/W

STATIC CHARACTERISTICS

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	Collector cut-off current ²	$V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax}$	-	-	1.0	mΑ
I _{CES}		$V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax}; $ $T_i = 125 \text{ °C}$	-	-	2.0	mA
BV _{EBO}	Emitter-base breakdown voltage	$I_{B} = 600 \text{ mA}$	7.5	12.5	-	V
R _{be}	Base-emitter resistance	$V_{FB} = 7.5 \text{ V}$	-	46	-	Ω
V _{CEOsust}	Collector-emitter sustaining voltage	I _B = 0 A; I _C = 100 mA; L = 25 mH	800	-	-	V
$V_{\sf CEsat}$	Collector-emitter saturation voltage	$I_{C} = 8 \text{ A}; I_{B} = 2 \text{ A}$	_	-	3.0	V
V _{BEsat}	Base-emitter saturation voltage	$I_{0} = 8 \text{ A}$: $I_{0} = 2 \text{ A}$	0.85	0.95	1.1	V
h _{FE}	DC current gain	$I_{\rm C} = 1 \text{A}; V_{\rm CE} = 5 \text{V}$	-	t.b.f	-	
		$I_{\rm C} = 8 \text{A}; V_{\rm CE} = 5 \text{V}$	4.2	5.8	7.3	
h _{FE} V _F	Diode forward voltage	$I_{\rm F} = 8.0 {\rm A}$	-	-	2.2	V

DYNAMIC CHARACTERISTICS

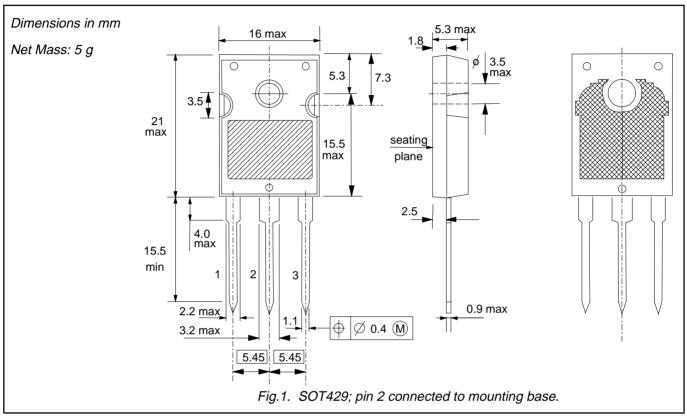
 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
	Switching times (16 kHz line deflection circuit)	$I_{Csat} = 8.0 \text{ A}; I_{B1} = 1.6 \text{ A}$ $(I_{B2} = -4.0 \text{ A})$			
t _s	Turn-off storage time Turn-off fall time		4.5 0.30	5.5 0.40	μs μs
	Switching times (70 kHz line deflection circuit)	$I_{Csat} = t.b.f$			
t _s	Turn-off storage time Turn-off fall time		t.b.f t.b.f	t.b.f t.b.f	μs μs

² Measured with half sine-wave voltage (curve tracer).

BU4523DW

MECHANICAL DATA



- Refer to mounting instructions for SOT429 envelope.
 Epoxy meets UL94 V0 at 1/8".

BU4523DW

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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